

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re patent application of

Mun-Pyo HONG, et al.

Docket no.: 6192.0158.D1

Serial No.: To Be Assigned

Group Art Unit: Unassigned

Filed: Concurrently Herewith

Examiner: Unassigned

For: **CONTACT STRUCTURE OF WIRING AND A THIN FILM TRANSISTOR
ARRAY PANEL INCLUDING THE SAME (AS AMENDED)**

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:

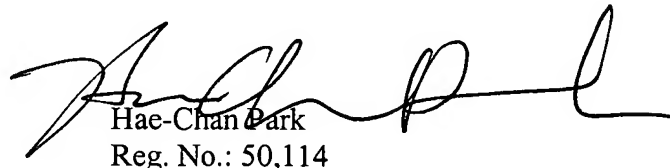
Under the provisions of 37 C.F.R. §1.97 through 1.99 and pursuant to applicants' duty of disclosure under 37 C.F.R. §1.56, applicants bring the documents, listed on PTO form 1449, to the attention of the Examiner in charge of the above-identified patent application. Copies of the references can be found in the parent case (U.S. Patent Application Serial No. 09/748,135).

This citation does not constitute an admission that the references are relevant or material to the claims. They are only cited as constituting related art of which the applicant is aware.

It is respectfully requested that the documents be considered by the Examiner and formally made of record in this application.

Please charge any deficiencies in payment and credit any overpayments to Attorney's deposit account number 23-1951 (McGuireWoods LLP).

Respectfully submitted,



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Reg. No.: 50,114

January 12, 2004
McGuireWoods LLP
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Form PTO-1449 (Modified) LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary)	Attorney Docket No.: 6192.0158.D1 Applicant: Mun-Pyo HONG, et al. Filing Date: January 12, 2004	Serial No.: Unassigned Group: Unassigned
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REFERENCE DESIGNATION

U.S. PATENT DOCUMENTS

EXAMINERS INITIALS	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE (IF APPRO.)
	5,969,377	10-1999	Seo, Seong Moh	257	72	
	5,340,761	10-1991	Loh, et al.	437	44	
	5,185,294	11-1991	Lam, et al	437	193	
	5,313,090	07-1991	Morikawa	257	577	
	6,395,586	02-1999	Huang et al.	438	149	
	6,043,512	09-1997	Adachi	257	66	
	6,218,206	09-1998	Inoue et al.	438	30	
	6,287,899	12-1999	Park et al.	438	149	
	5,677,240	05-1995	Murakami et al.	437	195	
	6,338,988	09-1999	Andry et al.	438	158	
	6,362,028	08-1999	Chen et al.	438	149	
	6,340,610	02-1999	Ahn et al.	438	158	
	5,573,959	05-1995	Kodaira et al.	437	21	
	6,274,412	12-1999	Kydd et al.	438	149	
	5,837,619	11-1995	Adachi et al.	438	795	
	6,159,779	02-1999	Huang et al.	438	158	
	5,734,177	09-1996	Sakamoto	257	49	
	6,017,779	02-1998	Miyasaka	438	149	
	5,289,030	03-1992	Yamazaki et al.	257	410	
	5,403,772	12-1993	Zhang et al.	437	101	

FOREIGN PATENT DOCUMENTS

DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES	NO
3-238714	10-1991	Japan	HO1B	13/00	<input type="checkbox"/>	<input type="checkbox"/>
					<input type="checkbox"/>	<input type="checkbox"/>
					<input type="checkbox"/>	<input type="checkbox"/>

OTHER ART (Including Author, Title, Date, Pertinent Pages, etc.)

	Ootani et al. "A 4-mb cmos sram with a pmos thin-film transistor load cell." IEEE journal of solid-state vol. 25 no. 5 10/90 pg. 1082-1092.
	Jin et al. "High-performance polysrystalline si-ge thin-film transistor using Al2O3 gate insulators". IEEE electron device letters vol. 19 no. 12 12/98 Pg. 502-504.
	Lan et al. "An alternative transparent conducting oxide to ito for the a-si:h TFT-LCD applications" AMLCDs '95 pg. 54-57.

EXAMINER

DATE CONSIDERED

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not conformance and not considered. Include copy of this form with next communication to applicant.